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**Vishay Semiconductors** 

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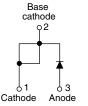
## Ultralow V<sub>F</sub> Hyperfast Rectifier for Discontinuous Mode PFC, 15 A FRED Pt<sup>®</sup>





TO-220AC

TO-220 FULL-PAK



VS-15ETL06PbF VS-15ETL06-N3 VS-15ETL06FPPbF VS-15ETL06FP-N3

Cathode

ტ 3

Anode

PRODUCT SUMMARY							
Package	TO-220AC, TO-220FP						
I <sub>F(AV)</sub>	15 A						
V <sub>R</sub>	600 V						
V <sub>F</sub> at I <sub>F</sub>	0.85 V						
t <sub>rr</sub> typ.	60 ns						
T <sub>J</sub> max.	175 °C						
Diode variation	Single die						

### FEATURES

- Hyperfast recovery time
- Benchmark ultralow forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- UL E78996 approved
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

State of the art, ultralow  $V_{F}$ , soft-switching hyperfast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

### APPLICATIONS

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V						
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 154 °C	15							
Average rectined forward current		T <sub>C</sub> = 120 °C (FULL-PAK)	15	А						
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	250	A						
Peak repetitive forward current	I <sub>FM</sub>		30							
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-	V			
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 15 A	-	0.99	1.05	V			
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	0.85	0.92				
Povoroo lookogo ourropt	je current I <sub>R</sub>	$V_{R} = V_{R}$ rated	-	0.1	10				
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	15	120	μA			
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	20	-	pF			
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH			

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1

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ J}$	A/μs, V <sub>R</sub> = 30 V	-	60	120				
		I <sub>F</sub> = 15 A, dI <sub>F</sub> /dt = 100 A/μs, V <sub>R</sub> = 30 V		-	190	270				
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	220	-	ns			
		T <sub>J</sub> = 125 °C	l <sub>F</sub> = 15 A dl <sub>F</sub> /dt = 200 A/µs	-	320	-				
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	19	-	А			
		T <sub>J</sub> = 125 °C	$V_{\rm R} = 390 \text{ V}$	-	26	-	~			
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	2.2	-				
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	]	-	4.3	-	μC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL TEST CONDITIONS			TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance,	P		-	1.0	1.3					
junction to case (FULL-PAK)	R <sub>thJC</sub>		-	3.0	3.5					
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W				
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-					
Wainht			-	2.0	-	g				
Weight			-	0.07	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking davias		Case style TO-220AC	15ETL06							
Marking device		Case style TO-220AC FULL-PAK	15ETL06FP							

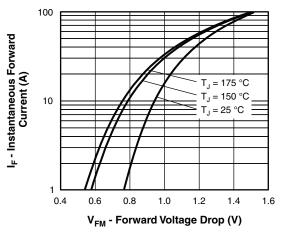
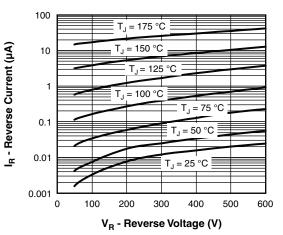
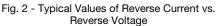


Fig. 1 - Maximum Forward Voltage Drop Characteristics





2

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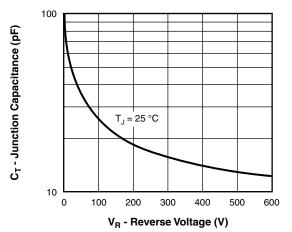


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

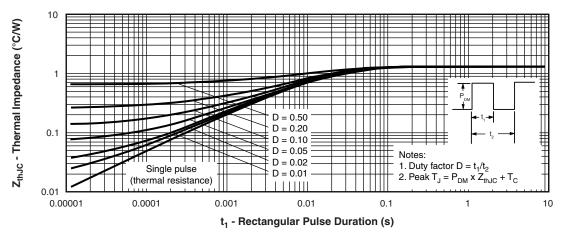


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

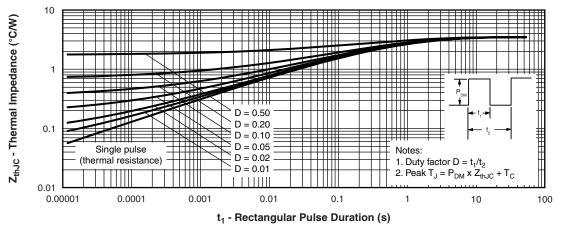
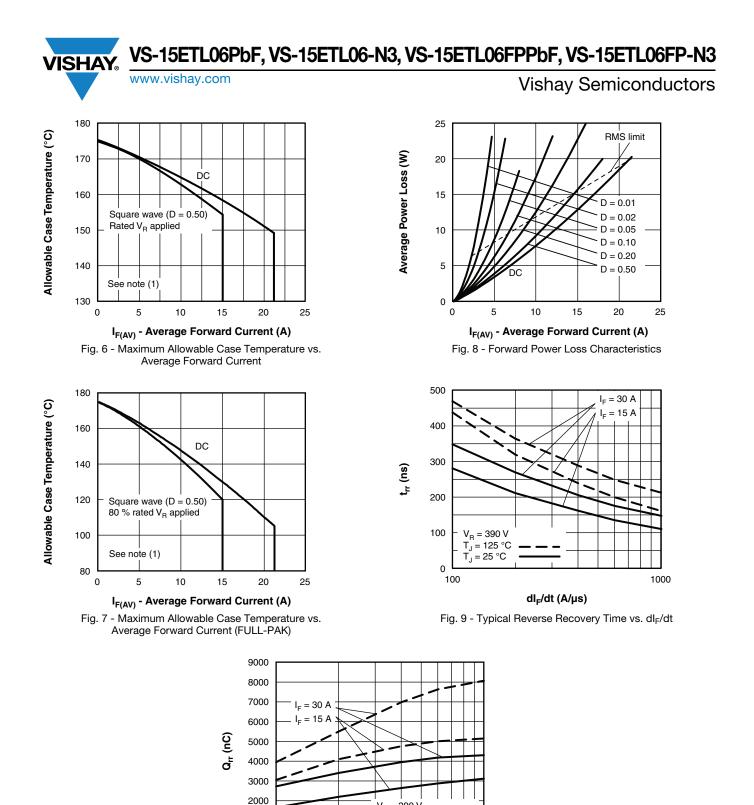


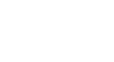
Fig. 5 - Maximum Thermal Impedance ZthJC Characteristics (FULL-PAK)

 Revision: 20-Oct-16
 3
 Document Number: 94004

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dl<sub>F</sub>/dt (A/µs) Fig. 10 - Typical Stored Charge vs. dl<sub>F</sub>/dt

V<sub>R</sub> = 390 V T<sub>1</sub> = 125 °C

T<sub>J</sub> = 25 °C

1000

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 8);  $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$ 

1000

0 100

Revision: 20-Oct-16

4

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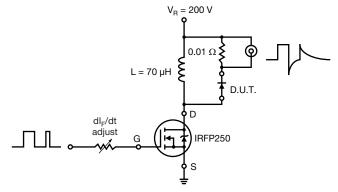
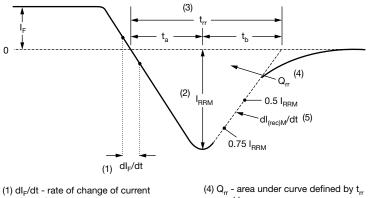


Fig. 11 - Reverse Recovery Parameter Test Circuit



- through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $I_{RRM}$  and 0.50  $I_{RRM}$ extrapolated to zero current.
- and I<sub>RRM</sub>

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

- (5)  $dI_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$
- Fig. 12 Reverse Recovery Waveform and Definitions

 Revision: 20-Oct-16
 5
 Document Number: 94004

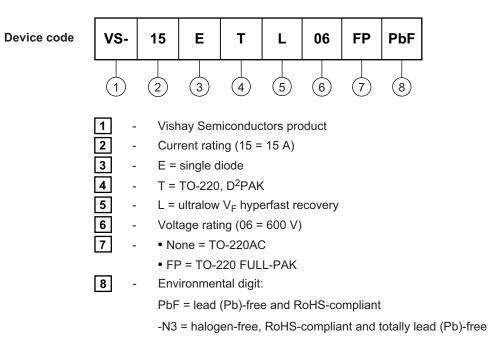
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## **Vishay Semiconductors**

### **ORDERING INFORMATION TABLE**

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ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-15ETL06PbF	50	1000	Antistatic plastic tube						
VS-15ETL06-N3	50	1000	Antistatic plastic tube						
VS-15ETL06FPPbF	50	1000	Antistatic plastic tube						
VS-15ETL06FP-N3	50	1000	Antistatic plastic tube						

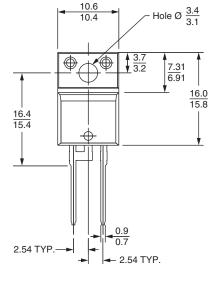
LINKS TO RELATED DOCUMENTS							
Dimensions	TO-220AC	www.vishay.com/doc?95221					
Dimensions	TO-220FP	www.vishay.com/doc?95005					
	TO-220ACPbF	www.vishay.com/doc?95224					
	TO-220AC-N3	www.vishay.com/doc?95068					
Part marking information	TO-220FPPbF	www.vishay.com/doc?95009					
	TO-220FP-N3	www.vishay.com/doc?95440					
SPICE model	TO-220AC	www.vishay.com/doc?96051					
	TO-220FP	www.vishay.com/doc?96052					



# **Outline Dimensions**

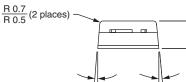
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### **DIMENSIONS** in millimeters

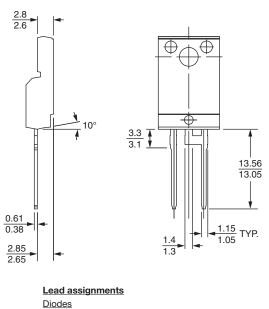


 $\frac{4.8}{4.6}$ 

 $5^{\circ} \pm 0.5^{\circ}$ 



 $5^{\circ} \pm 0.5^{\circ}$ 



<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Anoue

Conforms to JEDEC outline TO-220 FULL-PAK

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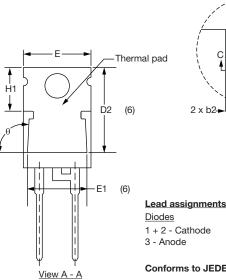
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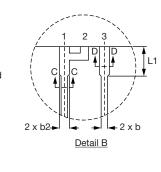
**TO-220AC** 

plane

### **DIMENSIONS** in millimeters and inches









**Diodes** 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STNDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
С	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØΡ	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- <sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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